Berezinski-Kosterlitz-Thouless transition in strongly disordered NbN films near the superconductor-insulator transition

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It is well accepted that, in two dimensions, the zero resistance state should be destroyed by the proliferation of phase fluctuations at a critical temperature $T_{BKT} < T_{c0}$, where T_{c0} is the mean-field transition temperature [1]. Experiments so far showed a strong broadening of the expected universal jump of the superfluid stiffness $J_S(T)$ at the Berezinski-Kosterlitz-Thouless (BKT) transition [2,3].

Here, we report AC and DC transport measurements of meso-scale NbN meanders, revealing a *sharp* BKT transition that is consistent in all experimental observables [4]. Reducing meander width from 20 μ m to 200 nm leads to the development of a foot in the resistive transition that clearly scales with the sample width. Our data can be understood in terms of established theory, without resorting to dominant sample inhomogeneity [1,5].

When increasing the normal state sheet resistance R_N up to 15 k Ω , T_{c0} , T_{BKT} and $J_S(0)$ decrease by nearly two orders of magnitude down to 0.2 K, while the BKT transition remains sharp. For the higher levels of disorder, the phase fluctuation regime $T_{BKT} < T < T_{c0}$ covers up to 85% of T_{c0} .

For strong disorder, numerical implementations of mean-field theory predict striking deviations from Anderson's theorem: the spectral gap E_g , the pair potential Δ , and the mean-field critical temperature T_{c0} all decrease and start to significantly deviate from each other [6]. The evolution of the measured $J_S(T)$ -curves with disorder reveals that another energy scale and not Δ determines $J_S(T)$ in the limit of strong disorder.

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